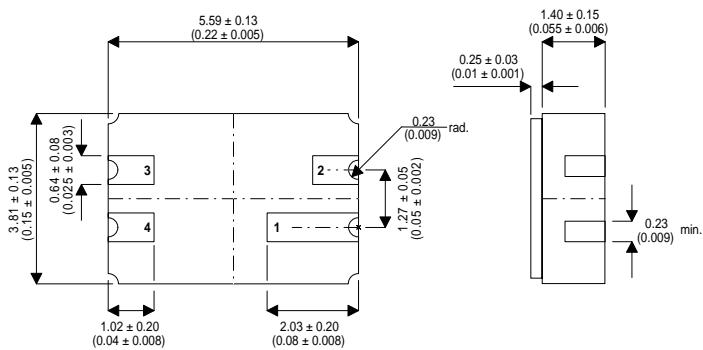




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IP431CSM4



LCC3 HERMETICALLY SEALED CERAMIC SURFACE MOUNT PACKAGE

PIN 1 - NOT CONNECTED
PIN 2 - CATHODE

PIN 3 - REFERENCE
PIN 4 - ANODE

PART NUMBER	AMBIENT TEMP. RANGE
IP431CSM4	-55 TO +125°C

PROGRAMMABLE PRECISION REFERENCE

FEATURES

- VOLTAGE REFERENCE TOLERANCE $\pm 1\%$
- PROGRAMMABLE OUTPUT VOLTAGE TO 36V
- EQUIVALENT FULL RANGE TEMPERATURE COEFFICIENT OF 30ppm/ $^{\circ}\text{C}$ TYPICAL
- TEMPERATURE COMPENSATED FOR OPERATION OVER FULL RATED OPERATING TEMPERATURE RANGE
- SINK CURRENT CAPABILITY 1 TO 100 mA
- FAST TURN-ON RESPONSE
- LOW DYNAMIC OUTPUT IMPEDANCE (0.2 Ω typical)
- LOW OUTPUT NOISE VOLTAGE

ABSOLUTE MAXIMUM RATINGS ($T_{\text{case}} = 25^{\circ}\text{C}$ unless otherwise stated)

V_{KA}	Cathode To Anode Voltage	37V
I_K	Cathode Current Range	-100 to +150mA
I_{REF}	Reference Input Current Range	-0.05 to +10mA
P_D	Power Dissipation @ $T_A = 25^{\circ}\text{C}$	0.80W
	Derate Above 25°C	6.4W/ $^{\circ}\text{C}$
T_J	Maximum Operating Junction Temperature	150°C
T_A	Operating Ambient Temperature Range	See Table Above
T_{STG}	Storage Temperature Range	-65 to 150°C



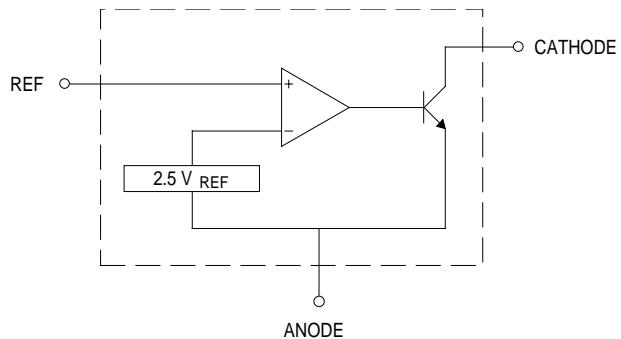
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IP431CSM4

DESCRIPTION

The IP431A circuit is a monolithic three terminal programmable shunt regulator diode. The voltage reference operates as a low temperature coefficient zener which is programmable between V_{REF} (2.5V) and 36 volts using two external resistors. The device has a wide operating current range of 1 mA to 100mA and a typical dynamic impedance of 0.2Ω . Active output circuitry provides a very sharp turn-on characteristic making these devices excellent replacements for zener diodes in many applications. Being a shunt regulator it can be used as either a positive or negative voltage reference.

BLOCK DIAGRAM



RECOMMENDED OPERATING CONDITIONS

V_{KA}	Cathode To Anode Voltage	V_{REF} to 36V
I_K	Cathode Current Range	1.0 to 100mA

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ C$ unless otherwise stated)

Parameter	Test Conditions	IP431AM			Units
		Min.	Typ.	Max.	
V_{REF} Reference Input Voltage (Figure 1)	$V_{KA} = V_{REF}$ $I_K = 10mA$ $T_A = -55 \text{ to } +125^\circ C^*$	2.47	2.495	2.52	V
		2.426		2.564	
ΔV_{REF} Reference Input Voltage Over Temperature Range 1 (Figure 1)	$V_{KA} = V_{REF}$ $I_K = 10mA$ $T_A = -55 \text{ to } +125^\circ C^*$		15	44	mV
$\frac{\Delta V_{REF}}{\Delta V_{KA}}$ Ratio of Reference Voltage Change to Change in Cathode to Anode Voltage (Figure 2)	$I_K = 10mA$ $\Delta V_{KA} = 10V \text{ to } V_{REF}$ $\Delta V_{KA} = 36V \text{ to } 10V$		-1.5	-2.7	
I_{REF} Reference Input Current (Figure 2)	$R1 = 10k\Omega$ $I_K = 10mA$ $T_A = -55 \text{ to } +125^\circ C^*$		1	4	μA
				7	
ΔI_{REF} Reference Input Current Deviation Over Temperature Range (Figure 2)	$R1 = 10k\Omega$ $I_K = 10mA$ $T_A = -55 \text{ to } +125^\circ C^*$		1	3	μA
I_{MIN} Minimum Cathode Current For Regulation (Figure 1)	$V_{KA} = V_{REF}$		0.5	1	mA
I_{OFF} Off-State Cathode Current (Figure 3)	$V_{KA} = 36V$ $V_{REF} = 0$		3	1000	nA
$ Z_{kal} $ Dynamic Impedance 2 (Figure 1)	$V_{KA} = V_{REF}$ $f \leq 1kHz$ $\Delta I_K = 1mA \text{ to } 100mA$		0.2	0.5	Ω



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IP431CSM4

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise stated)

Parameter	Test Conditions	IP431AI			Units	
		Min.	Typ.	Max.		
V_{REF}	Reference Input Voltage (Figure 1)	$V_{KA} = V_{\text{REF}}$ $I_K = 10\text{mA}$	2.47 2.44	2.495	2.52 2.55	V
ΔV_{REF}	Reference Input Voltage Over Temperature Range 1 (Figure 1)	$V_{KA} = V_{\text{REF}}$ $I_K = 10\text{mA}$	$T_A = -40 \text{ to } +85^\circ\text{C}^*$	7	30	
$\frac{\Delta V_{\text{REF}}}{\Delta V_{KA}}$	Ratio of Reference Voltage Change to Change in Cathode to Anode Voltage (Figure 2)	$I_K = 10\text{mA}$	$\Delta V_{KA} = 10\text{V to } V_{\text{REF}}$ $\Delta V_{KA} = 36\text{V to } 10\text{V}$	-1.5 -0.7	-2.7 -2	mV/V
I_{REF}	Reference Input Current (Figure 2)	$R1 = 10\text{k}\Omega$ $I_K = 10\text{mA}$	$R2 = \infty$ $T_A = -40 \text{ to } +85^\circ\text{C}^*$	1 6.5	4	
ΔI_{REF}	Reference Input Current Deviation Over Temperature Range (Figure 2)	$R1 = 10\text{k}\Omega$ $I_K = 10\text{mA}$	$R2 = \infty$ $T_A = -40 \text{ to } +85^\circ\text{C}^*$	0.8	2.5	μA
I_{MIN}	Minimum Cathode Current For Regulation (Figure 1)	$V_{KA} = V_{\text{REF}}$		0.5	1	mA
I_{OFF}	Off-State Cathode Current (Figure 3)	$V_{KA} = 36\text{V}$	$V_{\text{REF}} = 0$	3	1000	nA
$ Z_{\text{kal}}$	Dynamic Impedance 2 (Figure 1)	$V_{KA} = V_{\text{REF}}$ $\Delta I_K = 1\text{mA to } 100\text{mA}$	$f \leq 1\text{kHz}$	0.2	0.5	Ω

Parameter	Test Conditions	IP431AC			Units	
		Min.	Typ.	Max.		
V_{REF}	Reference Input Voltage (Figure 1)	$V_{KA} = V_{\text{REF}}$ $I_K = 10\text{mA}$	2.47 2.453	2.495	2.52 2.537	V
ΔV_{REF}	Reference Input Voltage Over Temperature Range 1 (Figure 1)	$V_{KA} = V_{\text{REF}}$ $I_K = 10\text{mA}$	$T_A = 0 \text{ to } +70^\circ\text{C}^*$	3	17	
$\frac{\Delta V_{\text{REF}}}{\Delta V_{KA}}$	Ratio of Reference Voltage Change to Change in Cathode to Anode Voltage (Figure 2)	$I_K = 10\text{mA}$	$\Delta V_{KA} = 10\text{V to } V_{\text{REF}}$ $\Delta V_{KA} = 36\text{V to } 10\text{V}$	-1.5 -0.7	-2.7 -2	mV/V
I_{REF}	Reference Input Current (Figure 2)	$R1 = 10\text{k}\Omega$ $I_K = 10\text{mA}$	$R2 = \infty$ $T_A = 0 \text{ to } +70^\circ\text{C}^*$	1 5.2	4	
ΔI_{REF}	Reference Input Current Deviation Over Temperature Range (Figure 2)	$R1 = 10\text{k}\Omega$ $I_K = 10\text{mA}$	$R2 = \infty$ $T_A = 0 \text{ to } +70^\circ\text{C}^*$	0.4	1.2	μA
I_{MIN}	Minimum Cathode Current For Regulation (Figure 1)	$V_{KA} = V_{\text{REF}}$		0.5	1	mA
I_{OFF}	Off-State Cathode Current (Figure 3)	$V_{KA} = 36\text{V}$	$V_{\text{REF}} = 0$	3	1000	nA
$ Z_{\text{kal}}$	Dynamic Impedance 2 (Figure 1)	$V_{KA} = V_{\text{REF}}$ $\Delta I_K = 1\text{mA to } 100\text{mA}$	$f \leq 1\text{kHz}$	0.2	0.5	Ω



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FIGURE 1
TEST CIRCUIT FOR $V_{KA} = V_{REF}$

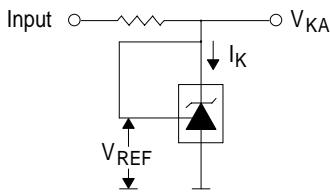


FIGURE 2
TEST CIRCUIT FOR $V_{KA} > V_{REF}$

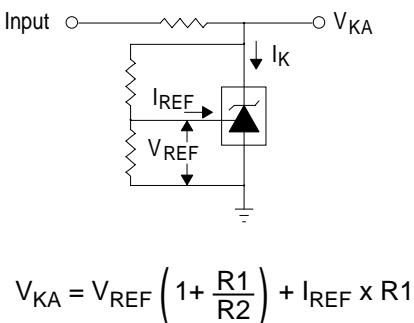
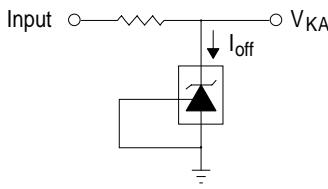
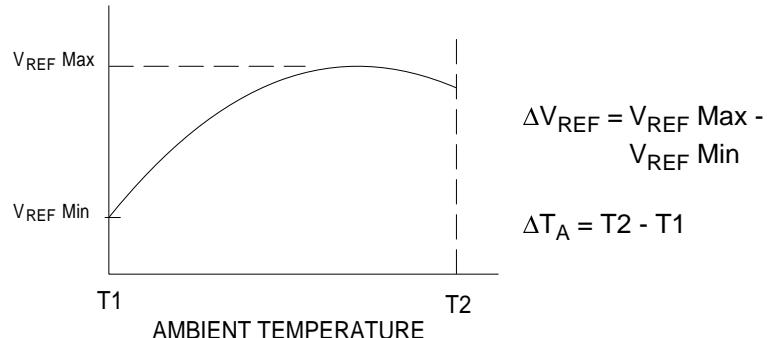


FIGURE 3
TEST CIRCUIT FOR I_{off}



NOTE 1

The deviation parameter ΔV_{REF} is defined as the differences between the maximum and minimum values obtained over the full operating ambient temperature range that applies.



The average temperature coefficient of the reference input voltage, $\propto V_{REF}$ is defined as:

$$\propto V_{REF} = \frac{\text{ppm}}{^\circ\text{C}} = \frac{\left(\frac{\Delta V_{REF}}{V_{REF} @ 25^\circ\text{C}} \right) \times 10^6}{\Delta T_A} = \frac{\Delta V_{REF} \times 10^6}{\Delta T_A (V_{REF} @ 25^\circ\text{C})}$$

$\propto V_{REF}$ can be positive or negative depending on whether $\propto V_{REF}$ Min or $\propto V_{REF}$ Max occurs at the lower ambient temperature.

Example: $\Delta V_{REF} = 8.0 \text{ mV}$ and slope is positive,
 $V_{REF} @ 25^\circ\text{C} = 2.495 \text{ V}$, $\Delta T_A = 70^\circ\text{C}$

$$\propto V_{REF} = \frac{0.008 \times 10^6}{70 (2.495)} = 45.8 \text{ ppm}/^\circ\text{C}$$

NOTE 2

The dynamic impedance Z_{ka} is defined as:

$$|Z_{ka}| = \frac{\Delta V_{KA}}{\Delta I_K}$$

When the device is programmed with two external resistors, R1 and R2, (refer to Figure 2) the total dynamic impedance of the circuit is defined as:

$$|Z_{kal}| \approx |Z_{kal}| \left(1 + \frac{R_1}{R_2} \right)$$